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Rev 1, 30-Oct-13

ActivePSR[™] Quasi-Resonant PWM Controller

FEATURES

- Patented Primary Side Regulation Technology
- Quasi-Resonant Operation
- Adjustable up to 120kHz Switching Frequency
- +/-5% Output Voltage Regulation
- Constant Power Operation Mode for Fast Start-up and Motor Drive Applications
- Integrated Line and Primary Inductance Compensation
- Built-in Soft-Start Circuit
- Line Under-Voltage, Thermal, Output Overvoltage, Output Short Protections
- Current Sense Resistor Short Protection
- Transformer Short Winding Protection
- Less than 100mW Standby Power
- Complies with Global Energy Efficiency and CEC Average Efficiency Standards
- Tinv SOT23-6 Packages

APPLICATIONS

- AC/DC Adaptors/Chargers for E-Shaver, Motor Driver, ADSL, Network Power, Cell Phone
- Big Capacitive Load Application

GENERAL DESCRIPTION

The ACT412 is a high performance peak current mode PWM controller which applies *ActivePSR*TM and *ActiveQR*TM technology. ACT412 achieves accurate voltage regulation without the need of an opto-coupler or reference device.

The ACT412 is designed to achieve less than 100mW Standby Power. By applying frequency fold back and *ActiveQR*TM technology, ACT412 exceeds the latest ES2.0 efficiency standard.

ACT412 integrates comprehensive protection. In case of over temperature, over voltage, short winding, short current sense resistor, open loop and overload conditions, it would enter auto restart

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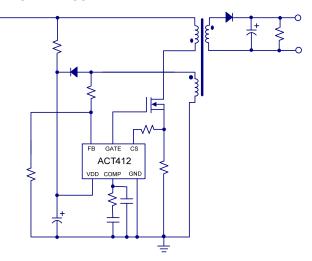
mode including cycle-by-cycle current limiting.

ACT412 is to achieve no overshoot and very short rise time even with big capacitive load ($10000\mu F$) with the built-in fast and soft start process, .

The Quasi-Resonant (QR) operation mode can effectively improve efficiency, reduce the EMI noise and further reduce the components in input filter.

ACT412 is idea for application up to 36 Watt.

Figure 1: Simplified Application Circuit

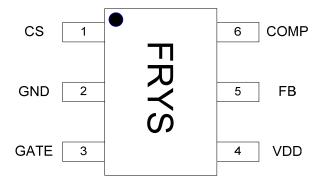




ORDERING INFORMATION

| PART NUMBER | TEMPERATURE RANGE | PACKAGE | PINS | PACKING METHOD | TOP MARK |
|-------------|----------------------|---------|------|-------------------|----------|
| ACT412US-T | -40°C to 85°C | SOT23-6 | 6 | TUBE & REEL | FRYS |

PIN CONFIGURATION



SOT23-6 ACT412US

PIN DESCRIPTIONS

| PIN | NAME | DESCRIPTION |
|-----|------|--|
| 1 | CS | Current Sense Pin. Connect an external resistor (R _{CS}) between this pin and ground to set peak current limit for the primary switch. |
| 2 | GND | Ground. |
| 3 | GATE | Gate Drive. Gate driver for the external MOSFET transistor. |
| 4 | VDD | Power Supply. This pin provides bias power for the IC during startup and steady state operation. |
| 5 | FB | Feedback Pin. Connect this pin to a resistor divider network from the auxiliary winding. |
| 6 | COMP | Compensation Pin. |

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ABSOLUTE MAXIMUM RATINGS®

| PARAMETER | VALUE | UNIT |
|--|--------------|------|
| FB, CS, COMP to GND | -0.3 to + 6 | V |
| VDD, GATE to GND | -0.3 to + 22 | V |
| Maximum Power Dissipation (SOT23-6) | 0.45 | W |
| Operating Junction Temperature | -40 to 150 | °C |
| Junction to Ambient Thermal Resistance (θ_{JA}) | 220 | °C/W |
| Operating Junction Temperature | -40 to 150 | °C |
| Storage Temperature | -55 to 150 | °C |
| Lead Temperature (Soldering, 10 sec) | 300 | °C |

①: Do not exceed these limits to prevent damage to the device. Exposure to absolute maximum rating conditions for long periods.

ELECTRICAL CHARACTERISTICS

 $(V_{DD}$ = 18V, L_M = 0.5mH, R_{CS} = 0.75 Ω , V_{OUT} = 13V, N_P = 68, N_S =12, N_A = 17, T_A = 25°C, unless otherwise specified,12V0.4A application)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT | |
|--|----------------------|---|-------|-------|-------|------|--|
| Supply | | | | | | | |
| VDD Turn-On Voltage | V_{DDON} | V _{DD} Rising from 0V | 11.11 | 12.35 | 13.58 | V | |
| VDD Turn-Off Voltage | V_{DDOFF} | V _{DD} Falling after Turn-on | 4.8 | 5.4 | 6 | V | |
| VDD Over Voltage Protection | V_{DDOVP} | V _{DD} Rising from 0V | 18.45 | 20.5 | 22.55 | V | |
| Start Up Supply Current | I _{DDST} | V _{DD} = 11V, before VDD Turn-on | | 5 | 10 | μA | |
| IDD Supply Current | I _{DD} | V _{DD} = 12V, after VDD Turn-on (no switching) | | 0.55 | 1 | mA | |
| IDD Supply Current at Fault Mode | I _{DD} | V _{DD} = 12V, after VDD Turn-on, fault = 1 | | 0.25 | | mA | |
| Feedback | | | | | | | |
| Effective FB Reference Voltage | V_{FBREF} | | 2.23 | 2.25 | 2.28 | V | |
| | _ | Light load | 0.38 | 0.45 | 0.52 | μs | |
| FB Sampling Blanking Time | T _{FB_BLK} | Heavy Load | 1.1 | 1.3 | 1.5 | μs | |
| Time needed for FB Sampling | _ | FB sampling | 0.5 | 0.65 | 0.75 | μs | |
| (After blanking) | T_{FB_SAMP} | CC and Knee point detecting | 0.22 | 0.25 | 0.29 | μs | |
| FB Leakage Current | I _{BVFB} | V _{FB} = 3V | | | 1 | μA | |
| Current Limit | | | | | | | |
| CC Commont Limit Throughold | V _{CSLIM1} | V _{OUT} = 12V | | 0.5 | | V | |
| CS Current Limit Threshold | V _{CSLIM2} | V _{OUT} = 6V | | 0.75 | | V | |
| CS Minimum Current Limits Threshold | V _{CSMIN} | | | 300 | | mV | |
| CS to GATE Propagation Delay | | | | 60 | | ns | |
| Loading Edgo Planking Time | т | Light Load | | 150 | | ns | |
| Leading Edge Blanking Time | T _{CSBLANK} | Heavy Load | | 636 | | ns | |



ELECTRICAL CHARACTERISTICS CONT'D

 $(V_{DD}$ = 18V, L_M = 0.5mH, R_{CS} = 0.75 Ω , V_{OUT} = 13V, N_P = 68, N_S =12, N_A = 17, T_A = 25°C, unless otherwise specified,12V0.4A application)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------------|------------------------|--|-----|------|-----|------|
| GATE DRIVE | • | | | | | • |
| Gate Rise Time | T _{RISE} | VDD = 10V, CL = 1nF | | 150 | 250 | ns |
| Gate Falling Time | T _{FALL} | VDD = 10V, CL = 1nF | | 90 | | ns |
| Gate Low Level ON-Resistance | R _{ONLO} | I _{SINK} = 30mA | | 10 | | Ω |
| Gate High Level ON-Resistance | R _{ONHI} | I _{SOURCE} = 30mA | | 31 | | Ω |
| Gate Leakage Current | | GATE = 18V, before VDD turn-on | | | 1 | μΑ |
| COMPENSATION | - | | | | | |
| Inside Compensate Resistor | R _{COMP} | ACT412 | | 0 | | kΩ |
| Output Sink Current | I _{COMP_SINK} | $V_{FB} = 3V$, $V_{COMP} = 2V$ | 15 | 40 | | μΑ |
| Output Source Current | I _{COMP_SOUR} | V _{FB} = 1.5V, V _{COMP} = 2V | 15 | 40 | | μA |
| Transconductance of Error Amplifier | Gm | | | 71 | | μA/V |
| Maximum Output Voltage | $V_{COMPMAX}$ | V _{FB} = 1.5V | | 3.5 | | V |
| Minimum Output Voltage | V _{COMPMIN} | V _{FB} = 3V | | 0.4 | | V |
| CS to COMP Gain | | | | 2 | | V/V |
| Pre-Amp Gain | | | | 1 | | V/V |
| COMP Leakage Current | | COMP = 2.5V | | | 1 | μA |
| OSCILLATOR | | | | | | |
| Maximum Switching | f _{MAX} | | 108 | 120 | 132 | kHz |
| Maximum Duty Cycle | D_{MAX} | | 65 | 75 | | % |
| Minimum Switching Frequency | f _{MIN} | | | 1164 | | Hz |



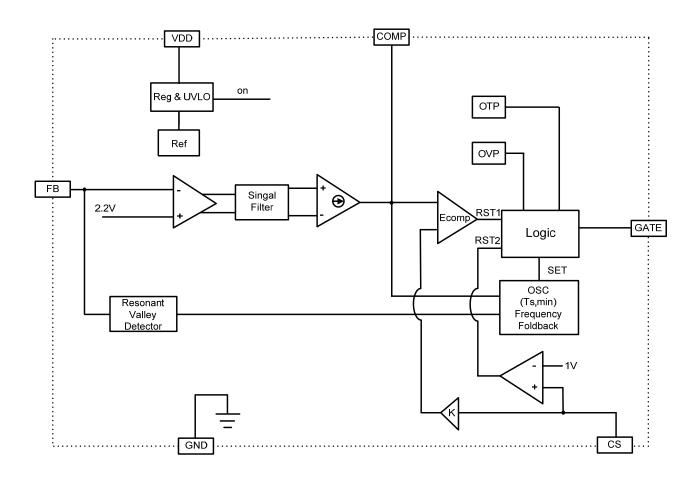
ELECTRICAL CHARACTERISTICS CONT'D

 $(V_{DD}$ = 18V, L_M = 0.5mH, R_{CS} = 0.75 Ω , V_{OUT} = 13V, N_P = 68, N_S =12, N_A = 17, T_A = 25°C, unless otherwise specified,12V0.4A application)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------------------|---------------------|---------------------------|-----|------|------|------|
| Protection | | | | | | |
| CS Short Waiting Time | | | 2 | 2.25 | 3 | μs |
| CS Short Detection Threshold | | | | 0.1 | 0.15 | V |
| CS Open Threshold Voltage | | | | 1.75 | | V |
| Abnormal OCP Blanking Time | | | | 190 | | ns |
| Inductance Short CS Threshold Voltage | | | | 1.75 | | V |
| Thermal Shutdown Temperature | | | | 135 | | °C |
| Thermal Hysteresis | | | | 20 | | °C |
| Vo Short Detection Threshold | V_{FBUVLO} | | | 0.28 | | V |
| Line UVLO | I _{FBUVLO} | | | 0.2 | | mA |
| Line UVLO Hysteresis | | | | 20 | | μA |
| Line OVP | I _{FBOVP} | | | 2.4 | | mA |
| VFB Over Voltage Protection | | | | 3 | | V |
| Valley Detection | | | | | | |
| Valley Detection Time Window | | V _{COMP} = 0.45V | | 3.3 | | μs |



FUNCTIONAL BLOCK DIAGRAM





FUNCTIONAL DESCRIPTION

ACT412 is a high performance peak current mode low-voltage PWM controller IC. The controller includes the most advance features that are required in the adaptor applications up to 36 Watt. Unique fast startup, frequency fold back, QR switching technique, accurate OLP, low standby mode operation, external compensation adjustment, short winding protection, OCP, OTP, OVP and UVLO are included in the controller.

Startup

Startup current of ACT412 is designed to be very low so that VDD could be charged to VDDON threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet reliable startup in application. For a typical AC/DC adaptor with universal input range design, two 1M Ω , 1/8 W startup resistors could be used together with a VDD capacitor(4.7uF) to provide a fast startup and yet low power dissipation design solution.

During startup period, the IC begins to operate with minimum lppk to minimize the switching stresses for the main switch, output diode and transformers. And then, the IC operates at maximum power output to achieve fast rise time. After this, V_{OUT} reaches about 90% V_{OUT} , the IC operates with a 'soft-landing' mode (decrease lppk) to avoid output overshoot.

Constant Voltage (CV) Mode Operation

In constant voltage operation, the ACT412 senses the output voltage at FB pin through a resistor divider network R5 and R6 in Figure 2. The signal at FB pin is pre-amplified against the internal reference voltage, and the secondary side output voltage is extracted based on Active-Semi's proprietary filter architecture.

This error signal is then amplified by the internal error amplifier. When the secondary output voltage is above regulation, the error amplifier output voltage decreases to reduce the switch current. When the secondary output voltage is below regulation, the error amplifier output voltage increases to ramp up the switch current to bring the secondary output back to regulation. The output regulation voltage is determined by the following relationship:

$$V_{OUTCV} = 2.20 V \times (1 + \frac{R_{FB1}}{R_{FB2}}) \times \frac{N_S}{N_A} - V_D$$
 (1)

where R_{FB1} (R5) and R_{FB2} (R6) are top and bottom feedback resistor, N_S and N_A are numbers of

transformer secondary and auxiliary turns, and V_{D} is the rectifier diode forward drop voltage at approximately 0.1A bias.

Constant Power (CP) Mode Operation

When the secondary output current reaches a level set by the internal current limiting circuit, the ACT412 enters current limit condition and causes the secondary output voltage to drop. As the output voltage decreases, so does the flyback voltage in a proportional manner. An internal current shaping circuitry adjusts the switching frequency and current limit threshold slowly based on the flyback voltage so that the transferred power is fixed to the output voltage, resulting in a constant power at secondary side output power profile. Through correctly setting K1, K2, the energy transferred to the output during each switching cycle is $\frac{1}{2}(LP \times ILIM^2)$, where LP is the transformer primary inductance, ILIM is the primary peak current, Formula can be present as below:

$$P_{OUTCP} = \frac{1}{2} \times L_{p} \times (K_{1}V_{CS_{-}TH})^{2} \times \eta \times K_{2}f_{SW}$$
 (2)

where f_{SW} is the switching frequency. The constant power operation typically extends down to 20% of nominal output voltage regulation.

Standby (No Load) Mode

In no load standby mode, the ACT412 oscillator frequency is further reduced to a minimum frequency while the current pulse is reduced to a minimum level to minimize standby power. The actual minimum switching frequency is programmable with an output preload resistor.

Loop Compensation

The ACT412 allows external loop compensation by connecting a capacitor to extend its applications, especially with different V_{OUT} in a wide output power range.

Primary Inductance Compensation

The ACT412 integrates a built-in primary inductance compensation circuit to maintain constant OLP despite variations in transformer manufacturing. The compensated ranges is +/-7%.

Primary Inductor Current Limit Compensation

The ACT412 integrates a primary inductor peak



FUNCTIONAL DESCRIPTION CONT'D

current limit compensation circuit to achieve constant power over wide line and wide load range.

Frequency Fold-back

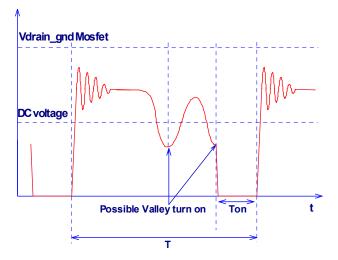
When the load drops to 75% of full load level, ACT412 starts to decrease the switching frequency, which is proportional to the load current ,to improve the efficiency of the converter as show in Functional Block Diagram.

This enables the application to meet all latest green energy standards. The actual minimum switching frequency is programmable with a small dummy load (while still meeting standby power).

Valley Switching

ACT412 employed valley switching from medium load to heavy load to reduce switching loss and EMI. After the switch is turned off, the ringing voltage from the auxiliary winding is applied to the VFB pin through feedback network R5, R6. Internally, the VFB pin is connected to an zero-crossing detector to generate the switch turn on signal when the conditions are met. In light load, the frequency fold back scheme starts to take control to determine the switch turn on signal, so thus the switching frequency.

Figure 1: Valley Switching at heavy load



Protection Features

The ACT412 provides full protection functions. The following table summarizes all protection functions.

Auto-Restart Operation

ACT412 will enter auto-restart mode when a fault is

identified. There is a startup phase in the autorestart mode. After this startup phase the conditions are checked whether the failure is still present. Normal operation proceeds once the failure mode is removed. Otherwise, new startup phase will be initiated again.

| PROTECTION FUNCTIONS | FAILURE CONDITION | PROTECTION MODE |
|----------------------------------|---|-----------------|
| V _{DD} Over Voltage | V _{DD} > 20.5V (4 duty cycle) | Auto Restart |
| VFB Over Voltage | V _{FB} > 3V (4 duty cycle) | Auto Restart |
| Over Temperature | T > 135°C | Auto Restart |
| Short Winding/ Short Diode | V _{CS} > 1.75V | Auto Restart |
| Over Load | IPK = I _{LIMIT} | Auto Restart |
| Output Short Circuit | V _{FB} < 0.28V | Auto Restart |
| Open Loop | No switching for 4 cycle | Auto Restart |
| V _{cc} Under Voltage | V _{CC} < 6.8V | Auto Restart |

To reduce the power loss during fault mode, the startup delay control is implemented. The startup delay time increases over lines.

Short Circuit Protection

When the secondary side output is short circuited, the ACT412 enters hiccup mode operation. This hiccup behavior continues until the short circuit is removed.

FB Over Voltage Protection

The ACT412 includes output over-voltage protection circuitry, which shuts down the IC when the output voltage is 40% above the normal regulation voltage 4 consecutive switching cycles. The ACT412 enters hiccup mode when an output over voltage fault is detected.

VDD Over Voltage Protection

ACT412 can monitor the converter output voltage. The voltage generated by the auxiliary winding tracks converter's output voltage through VDD, which is in proportion to the turn ratio ($V_{\text{OUT}}+V_{\text{DIODE}}$) xN_A/N_S. When the V_{OUT} is abnormally higher than design value for four consecutive cycles, IC will



TYPICAL APPLICATION CONT'D

enter the restart process. A counter is used to reduce sensitivity to noise and prevent the auto start unnecessary.

Open Loop Protection

ACT412 is able to protect itself from damage when the control loop is open. The typical open loop condition includes either VFB floating or RFB5 open.

Over Temperature Shutdown

The thermal shutdown circuitry detects the ACT412 die temperature. The threshold is set at typical 135°C. When the die temperature rises above this threshold (135°C) the ACT412 is disabled and remains disabled until the die temperature falls below 115°C, at which point the ACT412 is reenabled.

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TYPICAL APPLICATION CONT'D

Design Example

The design example below gives the procedure for a DCM fly back converter using an ACT412. Refer to Application Circuit Figure 2, the design for an adapter application starts with the following specification:

| Input Voltage Range | 90VAC - 265VAC, 50/60Hz |
|------------------------------------|-------------------------|
| Output Power, Po | 5W |
| Output Voltage, V _{OUTCV} | 12V |
| Full Load Current, IOUTFL | 0.4A |
| CC Current, I _{OUTMAX} | 1.8A |
| System Efficiency CV, η | 0.75 |

The operation for the circuit shown in Figure 1 is as follows: the rectifier bridge D1-D4 and the capacitor C1/C2 convert the AC line voltage to DC. This voltage supplies the primary winding of the transformer T1 and the startup resistor R7/R8 to VDD pin of ACT412 and C4. The primary power current path is formed by the transformer's primary winding, the mosfet, and the current sense resistor R9. The resistors R3, R2, diode D5 and capacitor C3 create a snubber clamping network that protects Q1 from voltage spike from the transformer primary leakage inductance. winding The network consisting of capacitor C4, diode D6 and resistor R4 provides a VDD supply voltage for ACT412 from the auxiliary winding of the transformer. The resistor R4 is optional, which filters out spikes and noise to makes VDD more stable. C4 is the decoupling capacitor of the supply voltage and energy storage component for startup. During power startup, the current charges C4 through startup resistor R7/R8 from the rectified high voltage. The diode D8 and the capacitor C5/C6 rectify filter the output voltage. The resistor divider consists of R5 and R6 programs the output voltage.

Since a bridge rectifier and bulk input capacitors are used, the resulting minimum and maximum DC input voltages can be calculated:

$$V_{INDC_MIN} = \sqrt{2V_{INAC_MIN}^2 \frac{2P_{OUT}(\frac{1}{2f_L} - t_C)}{\eta \times C_{IN}}}$$

$$= \sqrt{2 \times 85^2 - \frac{2 \times 5 \times (\frac{1}{2 \times 47} - 3.5 ms)}{0.75 \times 2 \times 6.8 \, \mu F}} \approx 90V$$
(3)

$$V_{IN(MAX)DC} = \sqrt{2} \times V_{IN(MAX)AC} = \sqrt{2} \times (265 V_{AC}) = 375 V$$
 (4)

Where η is the estimated circuit efficiency, f_L is the

line frequency, t_{C} is the estimated rectifier conduction time, C_{IN} is empirically selected to be 2x6.8µF electrolytic capacitors.

The full load system duty cycle is set to be 40% at low line voltage 85VAC and the circuit efficiency is estimated to be 75%. Then the average input current at full load is:

$$I_{IN _{-}FL} = \frac{P_{OUT _{-}FL}}{V_{INDC _{-}MIN} \times \eta}$$

$$= \frac{5}{90 \times 0.75} \approx 75 \text{ mA}$$
(5)

The input primary peak current at full load:

$$I_{ppk_FL} = \frac{2 \times L_{IN_FL}}{D_{Fl}} = \frac{2 \times 75}{0.4} = 375 \text{ mA}$$
 (6)

The primary inductance of the transformer:

$$L_{p} = \frac{V_{INDC} - MIN D_{FL}}{I_{ppk} - FL \times f_{s}}$$

$$= \frac{90 \times 0.4}{375 \text{ mA} \times 130 \text{ k}} \approx 0.74 \text{ mH}$$
(7)

The primary turns on time at full load:

$$T_{ON_FL} = L_p \frac{I_{ppk_FL}}{V_{INDC_MIN}}$$

= $\frac{0.74 \text{ mH} \times 375 \text{ mA}}{90} = 3.08 \,\mu\text{s}$ (8)

The ringing periods from primary inductance with mosfet Drain-Source capacitor:

$$T_{RINGING_MAX} = 2\pi \sqrt{L_{p_MAX} C_{DS_MAX}}$$

$$= 2 \times 3.14 \times \sqrt{0.73 \, \text{mH} \times (1 + 7\%) \times 100 \, \text{PF}} = 1.76 \, \mu \text{s}$$
(9)

Design only an half ringing cycle at maximum load in minimum low line, so secondly reset time:

$$T_{RST} = T_{SW} - T_{ON_FL} - 0.5T_{RINGING_MAX}$$

= 1/130kHz - 3.08 \(\mu\sigma\) s - 0.5 \times 1.76 \(\mu\sigma\) s = 3.73 \(\mu\sigma\)

Base on conservation of energy and transformer transform identity, the primary to secondary turns ratio N_P/N_S :

$$\frac{N_P}{N_S} = \frac{T_{ON}}{T_{RST}} \times \frac{V_{IN_MIN}}{V_{OUT} + V_D}$$

$$= \frac{3.08}{3.73} \times \frac{90}{13 + 0.45} = 5.53$$
(11)

The auxiliary to secondary turns ratio N_A/N_S:

$$\frac{N_A}{N_S} = \frac{V_{DD} + V_D'}{V_{OUT} + V_D} = \frac{18 + 0.45}{13 + 0.45} = 1.37$$
 (12)



TYPICAL APPLICATION CONT'D

An EE16 core is selected for the transformer. From the manufacture's catalogue recommendation, the core with an effective area A_E is 19.2mm^2 . The turn of the primary winding is:

$$N_{P} \ge \frac{I_{lim} \times L_{P_max}}{A_{E} \times B_{max}} = \frac{0.75 \times 0.00073}{19.2 \times 3000 \times 10^{-10}} = 95T$$
 (13)

$$I_{lim} = 2 \times I_{p_{-}FL} = 2 \times 375 \text{ mA} \approx 750 \text{ mA}$$
 (14)

The turns of secondary and auxiliary winding can be derived accordingly:

$$N_s = N_p / \frac{N_p}{N_s} = 95 / 5.53 \approx 17 T$$

$$N_A = \frac{N_A}{N_s} \times N_s = 1.4 \times 17 \approx 24 T$$
(15)

Determining the value of the current sense resistor (R9) uses the peak current in the design. Since the ACT412 internal current limit is set to 1V, the design of the current sense resistor is given by:

$$R_{CS} = \frac{V_{CS}}{I_{lim}} = \frac{1}{0.75} \approx 1.3.\Omega$$
 (16)

The voltage feedback resistors are selected according to frequency at full load. The design frequency at full load is given by:

$$f_{s} = \frac{N_{p}}{N_{s}} \times \frac{R_{fb1} \times R_{fb2}}{R_{fb1} + R_{fb2}} \times \frac{V_{O} + V_{D}}{L_{p} \times \frac{V_{cs}}{R_{cs}} \times K_{f_{-sw}}}$$
(17)

The design Vo is given by:

$$V_o = (1 + \frac{R_{fb1}}{R_{fb2}}) \times \frac{N_s}{N_a} \times V_{FB} - V_D$$
 (18)

Where k is IC constant and K=0.0000065, then we can get the value:

$$R_{fb1} = 45.3 \, \text{K}, R_{fb2} = 6.9 \, \text{K} \tag{19}$$

When selecting the output capacitor, a low ESR electrolytic capacitor is recommended to minimize ripple from the current ripple. The approximate equation for the output capacitance value is given by:

$$C_{OUT} = \frac{I_{OUT}}{f_{SW} \times V_{BIDDIE}} = \frac{1.8}{110k \times 50mV} = 327\mu F$$
 (20)

Two $330\mu\text{F}$ electrolytic capacitors are used to keep the ripple small.

In fact, consider of transformer production, we scale

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down the turn ratio and inductance.

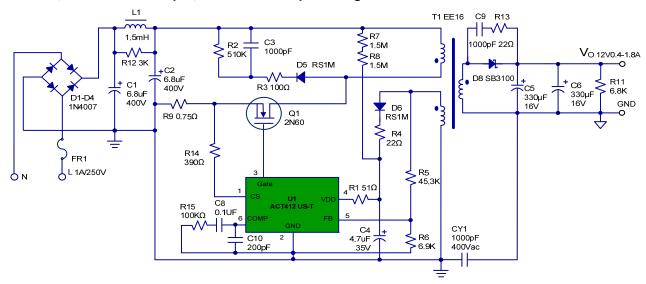
$$N_p = 68T, N_s = 12T, N_A = 17T, L_p = 0.5 \text{ mH}$$
 (21)

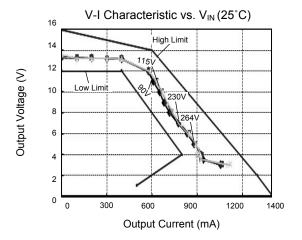
PCB Layout Guideline

Good PCB layout is critical to have optimal performance. Decoupling capacitor (C4) and feedback resistor (R5/R6) should be placed close to VDD and FB pin respectively. There are two main power path loops. One is formed by C1/C2, primary winding, Mosfet transistor and current sense resistor (R9). The other is secondary winding, rectifier D8 and output capacitors (C5/C6). Keep these loop areas as small as possible. Connecting high current ground returns, the input capacitor ground lead, and the ACT412 GND pin to a single point (star ground configuration).



Figure 2:
ACT412, Universal VAC Input, 12V/400mA Output Charger





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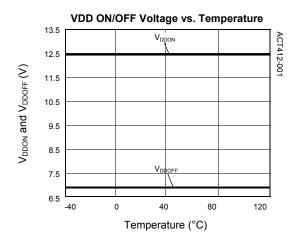
Table 2: ACT412 Bill of Materials

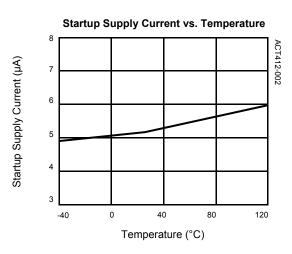
| ITEM | REFERENCE | DESCRIPTION | QTY | MANUFACTURER |
|------|-----------|---|-----|--------------|
| 1 | U1 | IC, ACT412,SOT23-6 | 1 | Active-Semi. |
| 2 | C1,C2 | Capacitor, Electrolytic, 6.8µF/400V, 10x12mm | 2 | KSC |
| 3 | C3 | Capacitor, Ceramic, 1000pF/500V, 0805,SMD | 1 | POE |
| 4 | C4 | Capacitor, Electrolytic,4.7µF/35V,5x11mm | 1 | KSC |
| 5 | C5,C6 | Capacitor, Electrolytic, 330µF/16V, 8x11.5mm | 2 | KSC |
| 6 | C8 | Capacitor, Ceramic, 0.1µF/25V, 0805,SMD | 1 | POE |
| 7 | C9 | Capacitor, Ceramic, 1000pF/100V, 0805,SMD | 1 | POE |
| 8 | C10 | Capacitor, Ceramic, 200pF/50V, 0805,SMD | 1 | POE |
| 9 | CY1 | Safety Y1,Capacitor,1000pF/400V,Dip | 1 | UXT |
| 10 | D1-D4 | Diode,Rectifier,1000V/1A,1N4007, DO-41 | 4 | Good-Ark |
| 11 | D5 | Fast Recovery Rectifier, RS1M,1000V/1.0A, RMA | 1 | PANJIT |
| 12 | D6 | Fast Recovery Rectifier,RS1D,200V/1.0A,SMA | 1 | PANJIT |
| 13 | D7 | NC | | |
| 14 | D8 | Diode, schottky, 100V/3A, SB3100, DO-47 | 1 | Good-Ark |
| 15 | L1 | Axial Inductor, 1.5mH, 5*7,Dip | 1 | SoKa |
| 16 | L2 | Axial Inductor, 0.55*5T, 5*7,Dip | 1 | SoKa |
| 17 | Q1 | Mosfet Transistor, 4N60,TO-220 | 1 | Infineon |
| 18 | PCB1 | PCB, L*W*T=52.2x30x1.6mm,Cem-1,Rev:A | 1 | Jintong |
| 19 | FR1 | Fuse,1A/250V | 1 | TY-OHM |
| 20 | R1 | Chip Resistor, 51Ω, 0805, 5% | 1 | TY-OHM |
| 21 | R2 | Chip Resistor, 510KΩ, 1206, 5% | 1 | TY-OHM |
| 22 | R3 | Chip Resistor, 100Ω, 0805, 5% | 1 | TY-OHM |
| 23 | R4,R13 | Chip Resistor, 22Ω, 0805, 5% | 2 | TY-OHM |
| 24 | R5 | Chip Resistor, 45.3KΩ, 0805,1% | 1 | TY-OHM |
| 25 | R6 | Chip Resistor, 6.9KΩ, 0805, 1% | 1 | TY-OHM |
| 26 | R7,R8 | Chip Resistor, 1.5MΩ, 0805 , 5% | 2 | TY-OHM |
| 27 | R9 | Chip Resistor, 0.75Ω, 1206,1% | 1 | TY-OHM |
| 28 | R11 | Chip Resistor, 6.8KΩ, 0805, 5% | 1 | TY-OHM |
| 29 | R12 | Chip Resistor, $3K\Omega$, 0805 , 5% | 1 | TY-OHM |
| 30 | R14 | Chip Resistor, 390Ω , 0805 , 5% | 1 | TY-OHM |
| 31 | R15 | Chip Resistor, $100K\Omega$, 0805 , 5% | 1 | TY-OHM |
| 32 | T1 | Transformer, Lp=0.5mH, EE16 | 1 | |

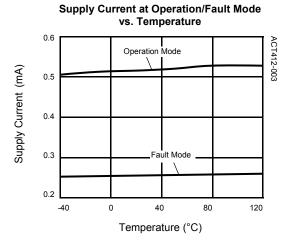
- 13 -

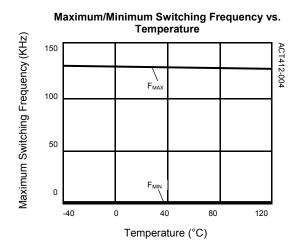


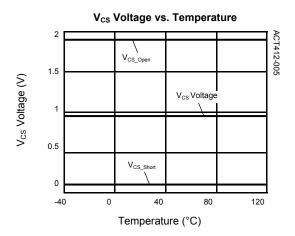
TYPICAL PERFORMANCE CHARACTERISTICS

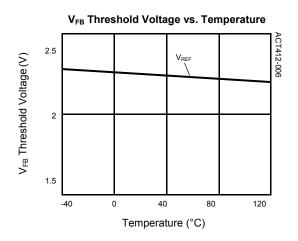






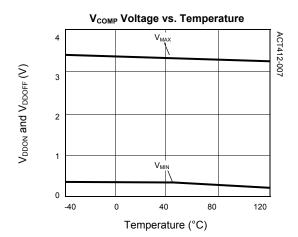








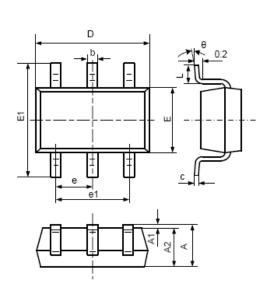
TYPICAL PERFORMANCE CHARACTERISTICS





PACKAGE OUTLINE

SOT23-6 PACKAGE OUTLINE AND DIMENSIONS



| SYMBOL | | SION IN ETERS | DIMENSION IN INCHES | | |
|--------|-------|------------------|------------------------|-------|--|
| | MIN | MAX | MIN | MAX | |
| Α | 1.050 | 1.250 | 0.041 | 0.049 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| С | 0.100 | 0.200 | 0.004 | 0.008 | |
| D | 2.820 | 3.020 | 0.111 | 0.119 | |
| Е | 1.500 | 1.700 | 0.059 | 0.067 | |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 | |
| е | 0.950 | TYP | 0.037 TYP | | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.700 | 0.700 REF | | REF | |
| L1 | 0.300 | 0.600 | 0.012 | 0.024 | |
| θ | 0° | 8° | 0° | 8° | |

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